



CSD25484F4 –20 V P-Channel FemtoFET™ MOSFET

1 Features

- Low On Resistance
- Ultra-Low Q_g and Q_{gd}
- Low Threshold Voltage
- Ultra-Small Footprint (0402 Case Size)
 - 1.0 mm × 0.6 mm
- Ultra-Low Profile
 - 0.2 mm Height
- Integrated ESD Protection Diode
 - Rated >4 kV HBM
 - Rated >2 kV CDM
- Lead and Halogen Free
- RoHS Compliant

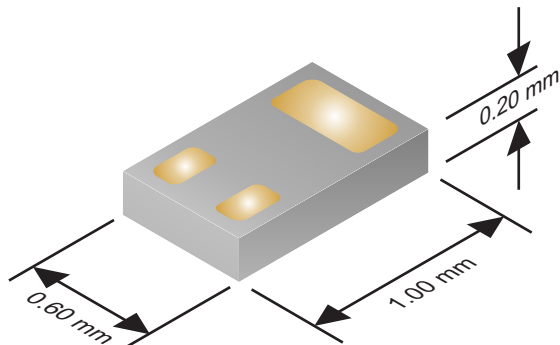
2 Applications

- Optimized for Load Switch Applications
- Optimized for General Purpose Switching Applications
- Battery Applications
- Handheld and Mobile Applications

3 Description

This 80 mΩ, –20 V P-Channel FemtoFET™ MOSFET is designed and optimized to minimize the footprint in many handheld and mobile applications. This technology is capable of replacing standard small signal MOSFETs while providing at least a 60% reduction in footprint size.

Typical Part Dimensions



Product Summary

$T_A = 25^\circ\text{C}$		TYPICAL VALUE		UNIT
V_{DS}	Drain-to-Source Voltage	–20		V
Q_g	Gate Charge Total (–4.5 V)	1090		pC
Q_{gd}	Gate Charge Gate-to-Drain	150		pC
$R_{DS(on)}$	Drain-to-Source On-Resistance	$V_{GS} = -1.8\text{ V}$	405	mΩ
		$V_{GS} = -2.5\text{ V}$	150	mΩ
		$V_{GS} = -4.5\text{ V}$	93	mΩ
		$V_{GS} = -8.0\text{ V}$	80	mΩ
$V_{GS(th)}$	Threshold Voltage	–0.95		V

Ordering Information⁽¹⁾

Device	Qty	Media	Package	Ship
CSD25484F4	3000	7-Inch Reel	Femto(0402) 1.0 mm × 0.6 mm Land Grid Array (LGA)	Tape and Reel
CSD25484F4T	250	7-Inch Reel		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$		VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	–20	V
V_{GS}	Gate-to-Source Voltage	–12	V
I_D	Continuous Drain Current ⁽¹⁾	–2.5	A
I_{DM}	Pulsed Drain Current ⁽¹⁾⁽²⁾	–22	A
I_G	Continuous Gate Clamp Current	–35	mA
	Pulsed Gate Clamp Current ⁽²⁾	–350	
P_D	Power Dissipation ⁽¹⁾	500	mW
ESD Rating	Human Body Model (HBM)	4	kV
	Charged Device Model (CDM)	2	kV
T_J, T_{stg}	Operating Junction and Storage Temperature Range	–55 to 150	°C

(1) Typical $R_{\theta JA} = 85^\circ\text{C/W}$ on 1 inch² (6.45 cm²), 2 oz. (0.071 mm thick) Cu pad on a 0.06 inch (1.52 mm) thick FR4 PCB.

(2) Pulse duration ≤100 μs, duty cycle ≤1%

Top View

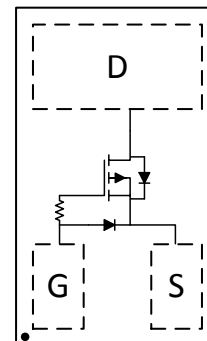


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4 Revision History

DATE	REVISION	NOTES
May 2015	*	Initial release.

5 Specifications

5.1 Electrical Characteristics

(T_A = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
STATIC CHARACTERISTICS							
BV _{DSS}	Drain-to-Source Voltage	V _{GS} = 0 V, I _{DS} = –250 μA	–20			V	
I _{DSS}	Drain-to-Source Leakage Current	V _{GS} = 0 V, V _{DS} = –16 V	–100			nA	
I _{GSS}	Gate-to-Source Leakage Current	V _{DS} = 0 V, V _{GS} = –12 V	–50			nA	
V _{GS(th)}	Gate-to-Source Threshold Voltage	V _{DS} = V _{GS} , I _{DS} = –250 μA	–0.7	–0.95	–1.2	V	
R _{DS(on)}	Drain-to-Source On-Resistance	V _{GS} = –1.8 V, I _{DS} = –0.1 A	405			825	mΩ
		V _{GS} = –2.5 V, I _{DS} = –0.5 A	150			180	mΩ
		V _{GS} = –4.5 V, I _{DS} = –0.5 A	93			109	mΩ
		V _{GS} = –8 V, I _{DS} = –0.5 A	80			94	mΩ
g _{fs}	Transconductance	V _{DS} = –10 V, I _{DS} = –0.5 A	3.5			S	
DYNAMIC CHARACTERISTICS							
C _{iSS}	Input Capacitance	V _{GS} = 0 V, V _{DS} = –10 V, f = 1 MHz	175			230	pF
C _{oSS}	Output Capacitance		78			102	pF
C _{rSS}	Reverse Transfer Capacitance		5.5			7.2	pF
R _G	Series Gate Resistance		20				Ω
Q _g	Gate Charge Total (–4.5 V)	V _{DS} = –10 V, I _{DS} = –0.5 A	1090			1415	pC
Q _{gd}	Gate Charge Gate-to-Drain		150				pC
Q _{gs}	Gate Charge Gate-to-Source		350				pC
Q _{g(th)}	Gate Charge at V _{th}		210				pC
Q _{oSS}	Output Charge	V _{DS} = –10 V, V _{GS} = 0 V	1290				pC
t _{d(on)}	Turn On Delay Time	V _{DS} = –10 V, V _{GS} = –4.5 V, I _{DS} = –0.5 A, R _G = 10 Ω	9.5				ns
t _r	Rise Time		5				ns
t _{d(off)}	Turn Off Delay Time		18				ns
t _f	Fall Time		8.5				ns
DIODE CHARACTERISTICS							
V _{SD}	Diode Forward Voltage	I _{SD} = –0.5 A, V _{GS} = 0 V	–0.75				V
Q _{rr}	Reverse Recovery Charge	V _{DS} = –10 V, I _F = –0.5 A, di/dt = 100 A/μs	970				pC
t _{rr}	Reverse Recovery Time		7.5				ns

5.2 Thermal Information

(T_A = 25°C unless otherwise stated)

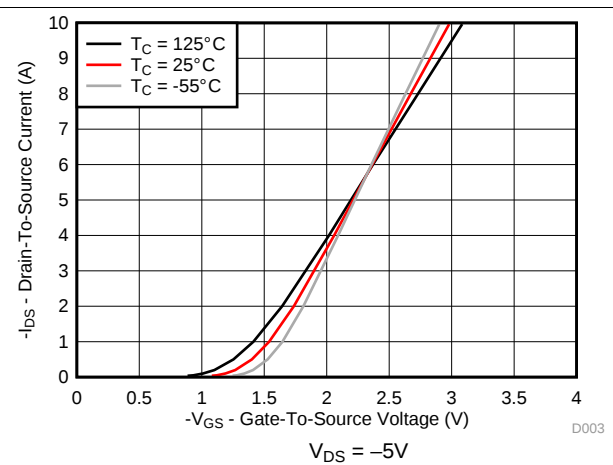
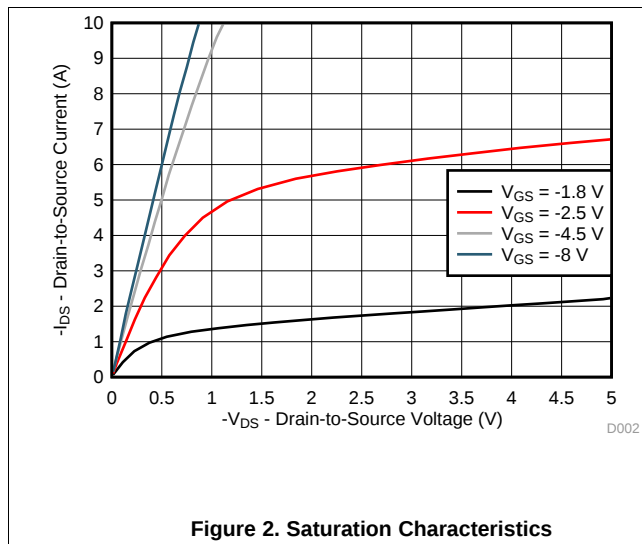
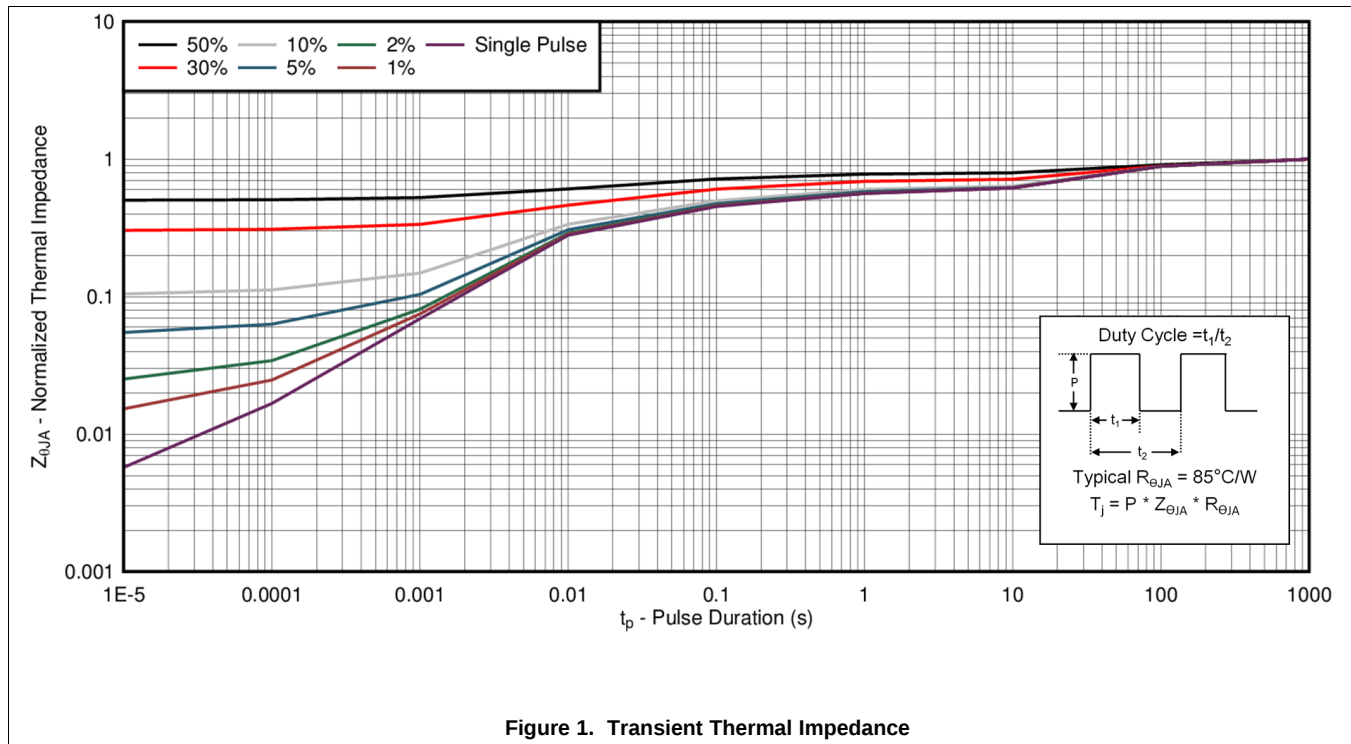
THERMAL METRIC		TYPICAL VALUES	UNIT
R _{θJA}	Junction-to-Ambient Thermal Resistance ⁽¹⁾	85	°C/W
	Junction-to-Ambient Thermal Resistance ⁽²⁾	245	

(1) Device mounted on FR4 material with 1 inch² (6.45 cm²), 2 oz. (0.071 mm thick) Cu.

(2) Device mounted on FR4 material with minimum Cu mounting area.

5.3 Typical MOSFET Characteristics

($T_A = 25^\circ\text{C}$ unless otherwise stated)



Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

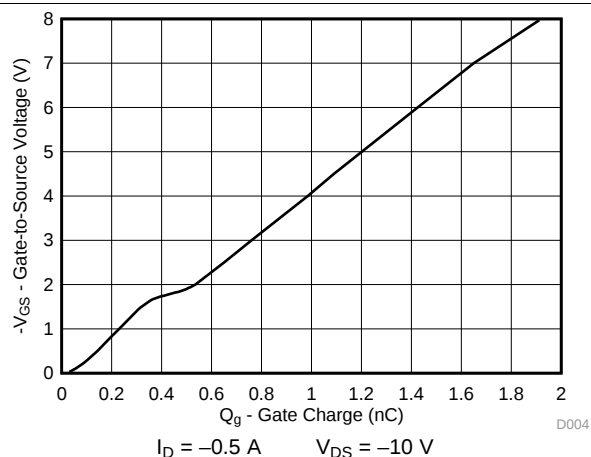


Figure 4. Gate Charge

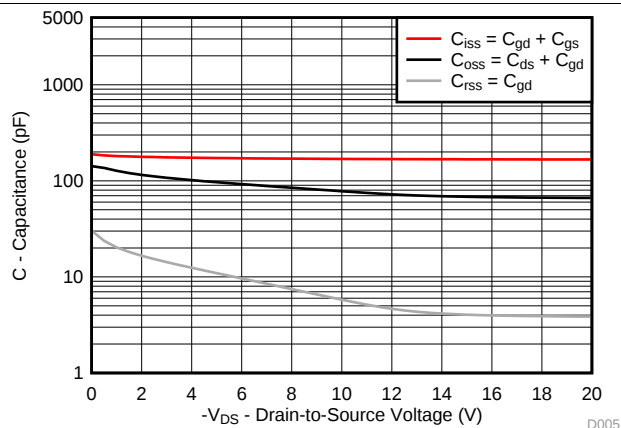


Figure 5. Capacitance

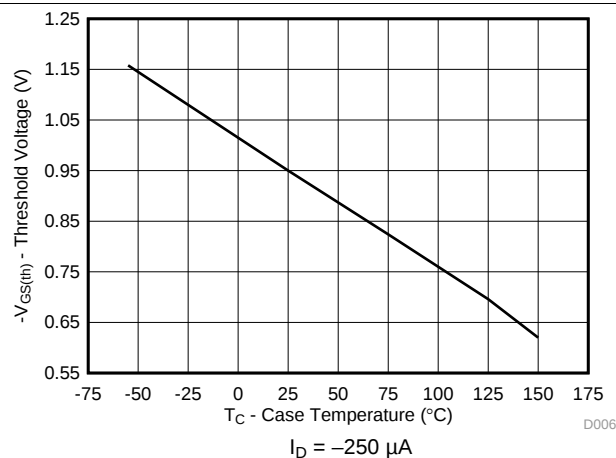


Figure 6. Threshold Voltage vs Temperature

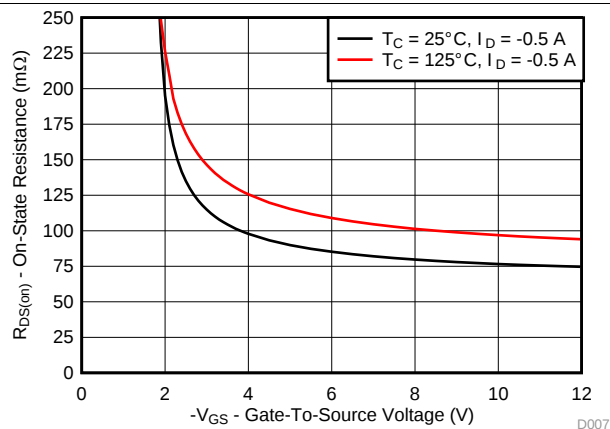


Figure 7. On-State Resistance vs Gate-to-Source Voltage

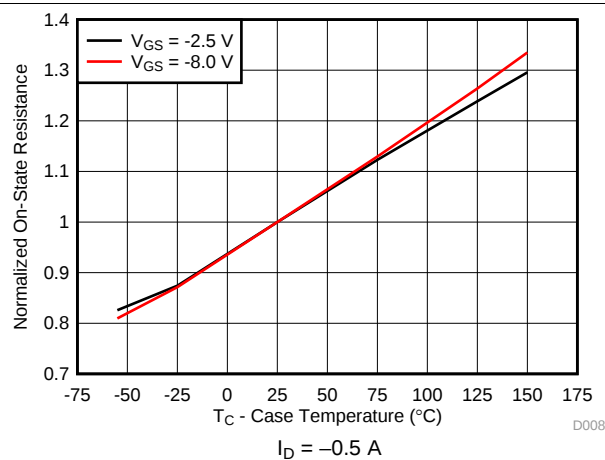


Figure 8. Normalized On-State Resistance vs Temperature

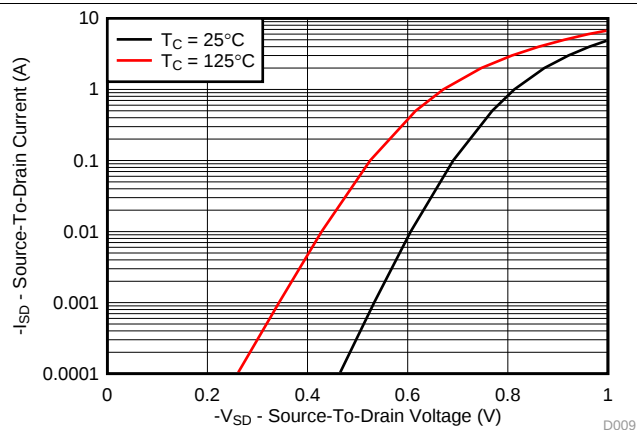
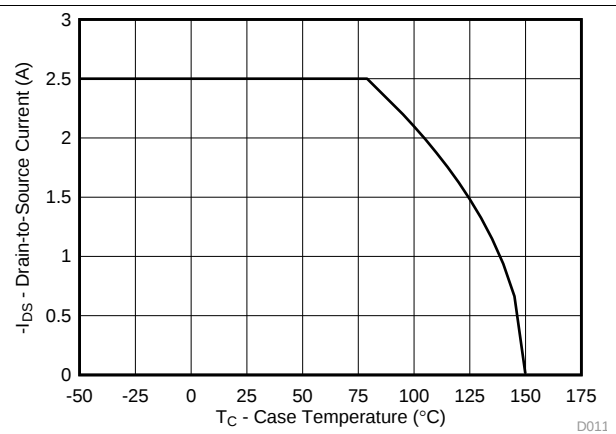
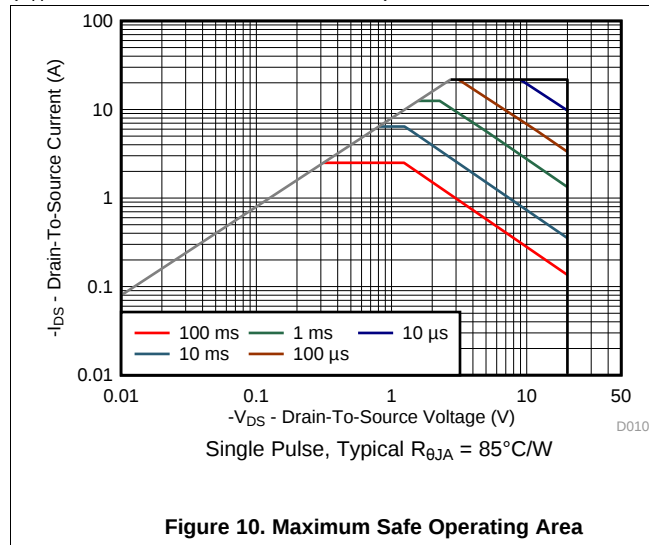


Figure 9. Typical Diode Forward Voltage

Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)



6 Device and Documentation Support

6.1 Trademarks

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6.2 Electrostatic Discharge Caution



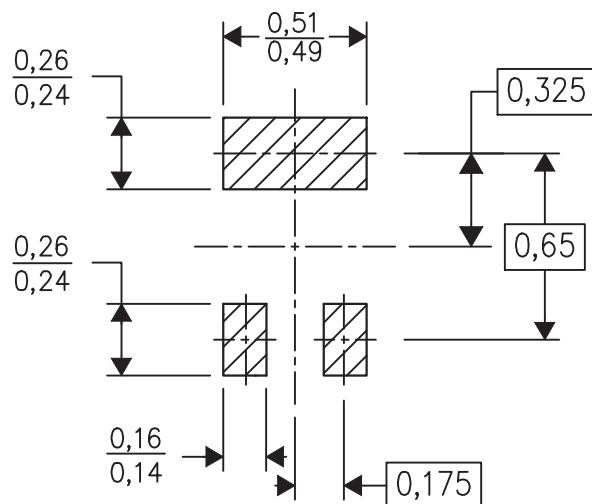
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.3 Glossary

[SLYZ022](#) — *TI Glossary*.

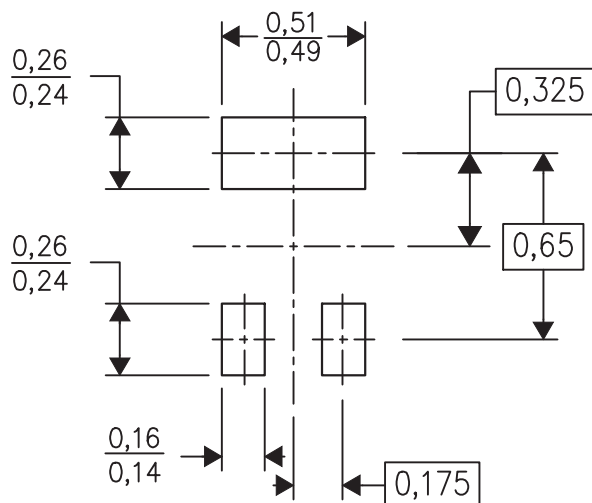
This glossary lists and explains terms, acronyms, and definitions.

7.2 Recommended Minimum PCB Layout



(1) All dimensions are in millimeters.

7.3 Recommended Stencil Pattern



(1) All dimensions are in millimeters.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD25484F4	ACTIVE	PICOSTAR	YJJ	3	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-55 to 150	YG3	Samples
CSD25484F4T	ACTIVE	PICOSTAR	YJJ	3	250	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-55 to 150	YG3	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD25484F4	PICOST AR	YJJ	3	3000	178.0	9.2	0.7	1.1	0.28	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD25484F4	PICOSTAR	YJJ	3	3000	220.0	220.0	35.0

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